NSN 5961-01-107-9560

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View Online at https://aerobasegroup.com/nsn/5961-01-107-9560
Inclosure Material:
Plastic
Overall Length:
0.363 inches
Overall Width:
0.408 inches
Mounting Facility Quantity:
1
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
75.0 nonrepetitive peak reverse voltage and 50.0 repetitive peak reverse voltage
Current Rating Per Characteristic:
2.50 amperes drain current universal and 4.00 amperes drain current horsepower metric and 2.75 amperes drain current nanoamperes
Power Rating Per Characteristic:
0.5 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Special Features:
One insulator and one washer included
Terminal Type And Quantity:
3 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A110a0